

Features

- Uses PingWei advanced PerfectMOS2 technology
- Extremely low on-resistance $R_{DS(on)}$
- Excellent $Q_g \times R_{DS(on)}$ product(FOM)
- Excellent Low Ciss
- 175°C operating temperature
- Top Side Cooling
- Qualified according to AEC-Q101 criteria

Applications

- General automotive applications

Benefits

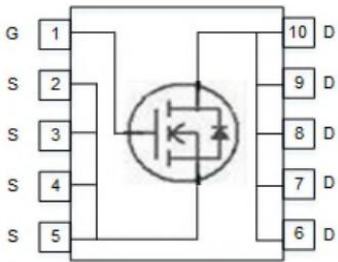
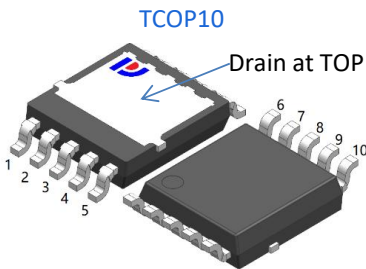
- High robustness and reliability
- Increases maximum current capability
- Low power loss, high power density
- Easy paralleling



100% DVDS Tested
100% Avalanche Tested

Product Summary

V_{DS}	40V
$R_{DS(on)}@10V\ typ$	0.64mΩ
$I_D\ (silicon\ limit)$	357A



Pins 10 - 6 & Tab on Drain

Package Marking and Ordering Information

Part #	Marking	Package	Packing	Reel Size	Tape Width	Qty
PWTC008N04PSQ	PWTC0804	TCOP10	Tape&Reel	13 inches	16mm	4500pcs

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	40	V
Continuous drain current $T_C = 25^{\circ}C$ (Silicon limit) $T_C = 25^{\circ}C$ (Package limit) $T_C = 100^{\circ}C$ (Silicon limit)	I_D	357 120 252	A
Pulsed drain current ($T_C = 25^{\circ}C$)	$I_{D\ pulse}$	480	A
Avalanche energy, single pulse ($L=0.1mH$)	E_{AS}	420	mJ
Gate-Source voltage	V_{GS}	± 20	V
Power dissipation $T_C = 25^{\circ}C$	P_{tot}	197	W
Operating junction and storage temperature	T_j, T_{stg}	-55...+175	$^{\circ}C$
Reflow soldering temperature (10s)	T_{sold}	260	$^{\circ}C$

Thermal Resistance

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.		
Thermal resistance, junction – case.	RthJC	-	-	0.76	°C/W	Juction to TOP Tab
Thermal resistance, junction - ambient	RthJA	-	-	57	°C/W	1 inch ² , 2oz single copper FR-4 PCB

Electrical Characteristic (at T_j = 25 °C, unless otherwise specified)

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.		

Static Characteristic

Drain-source breakdown voltage	BV _{DSS}	40	-	-	V	V _{GS} =0V, I _D =250uA
Gate threshold voltage	V _{GS(th)}	2.0	-	3.5	V	V _{DS} =V _{GS} , I _D =250uA
Zero gate voltage drain current	I _{DSS}	-	-	1 100	μA	V _{DS} =40V, V _{GS} =0V T _j =25°C T _j =125°C
Gate-source leakage current	I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0V
Drain-source on-state resistance	R _{DS(on)}	-	0.64	0.79	mΩ	V _{GS} =10V, I _D =30A
Transconductance	g _{fs}	-	120	-	S	V _{DS} =5V, I _D =30A

Dynamic Characteristic

Input Capacitance	C _{iss}	-	6895	10342	pF	V _{GS} =0V, V _{DS} =20V, f=100KHz
Output Capacitance	C _{oss}	-	2394	3590		
Reverse Transfer Capacitance	C _{rss}	-	73	147		
Gate Total Charge	Q _G	-	94	188	nC	V _{DS} =20V, I _D =30A , V _{GS} =10V
Gate-Source charge	Q _{GS}	-	29	59		
Gate-Drain charge	Q _{GD}	-	13	38		
Turn-on delay time	t _{d(on)}	-	19	-	ns	V _{GS} =10V, V _{DD} =20V, R _{G_ext} =1.6Ω, I _D =20A
Rise time	t _r	-	35	-		
Turn-off delay time	t _{d(off)}	-	66	-		
Fall time	t _f	-	20	-		
Gate resistance	R _G	-	2.9	-	Ω	V _{GS} =0V, V _{DS} =0V, f=1MHz

Body Diode Characteristic

Parameter	Symbol	Value			Unit	Test Condition
		min.	typ.	max.		
Body Diode Forward Voltage	V_{SD}	-	-	1.2	V	$V_{GS}=0V, I_{SD}=30A$
Body Diode Continuous Forward Current	I_S	-	-	120	A	TC = 25°C
Body Diode Pulsed Current	I_S pulse	-	-	480	A	TC = 25°C
Body Diode Reverse Recovery Time	t_{rr}	-	50	-	ns	$I_F=50A,$ $dI/dt=100A/\mu s$
Body Diode Reverse Recovery Charge	Q_{rr}	-	53	-	nC	

Typical Performance Characteristics

Fig 1: Output Characteristics

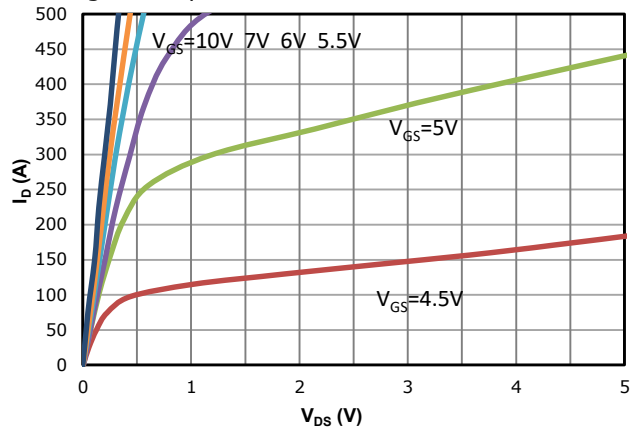


Fig 2: Transfer Characteristics

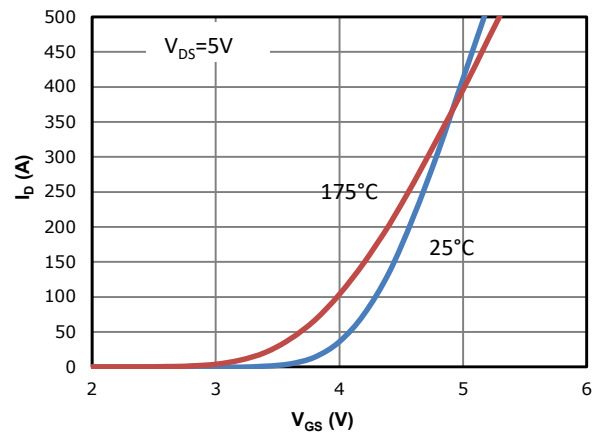


Fig 3: Rds(on) vs Drain Current and Gate Voltage

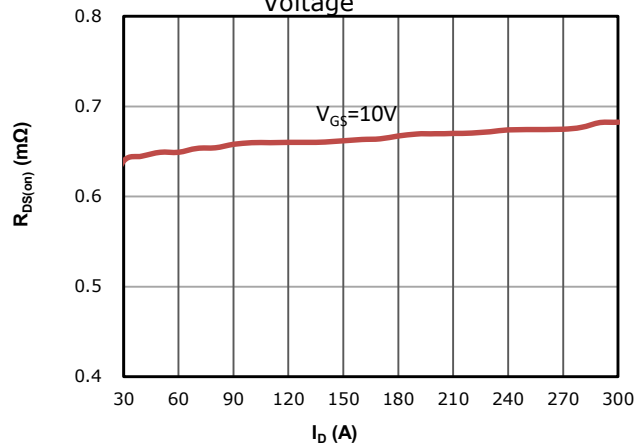


Fig 4: Rds(on) vs Gate Voltage

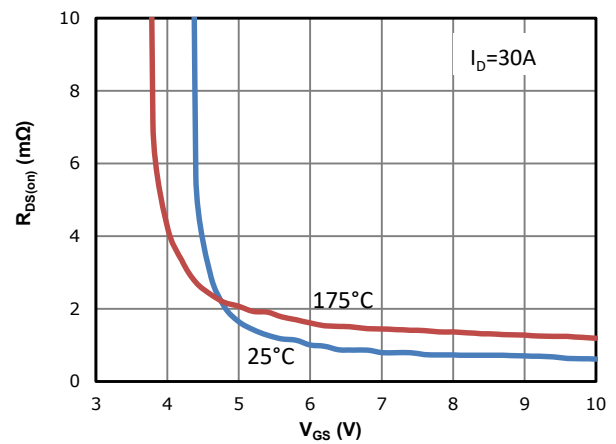


Fig 5: Rds(on) vs. Temperature

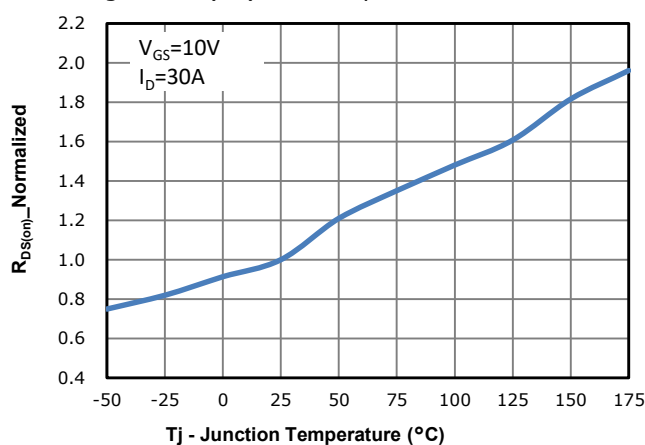


Fig 6: Vgs(th) vs. Temperature

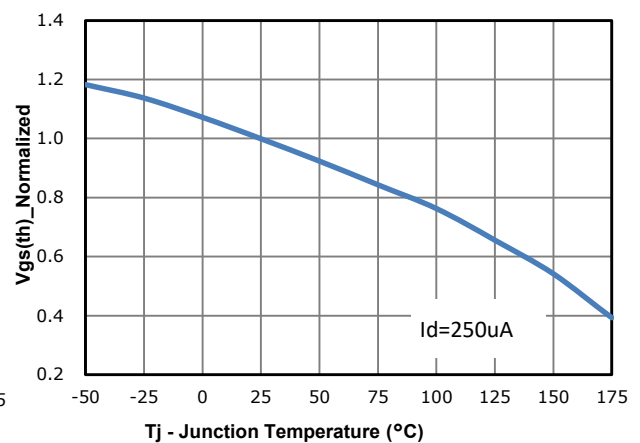


Fig 7: BVdss vs. Temperature

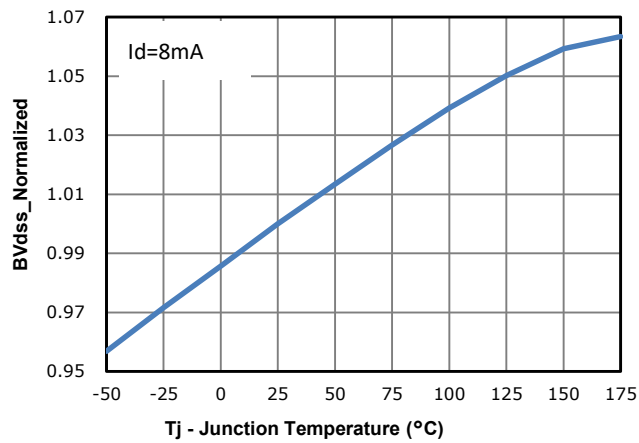


Fig 8: Capacitance Characteristics

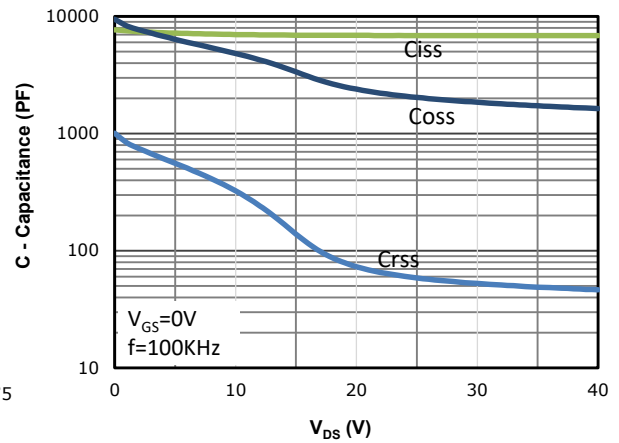


Fig 9: Gate Charge Characteristics

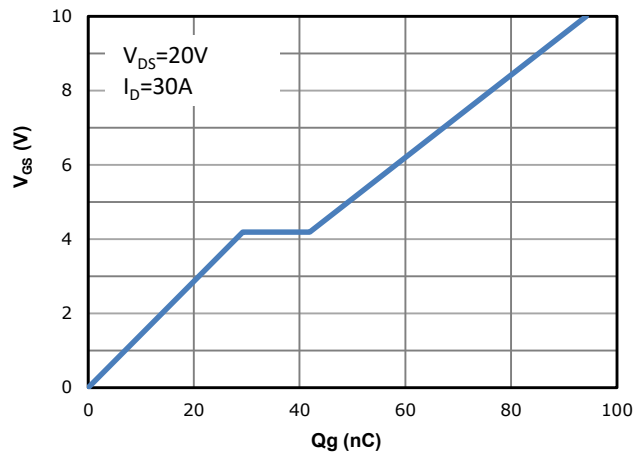


Fig 10: Body-diode Forward Characteristics

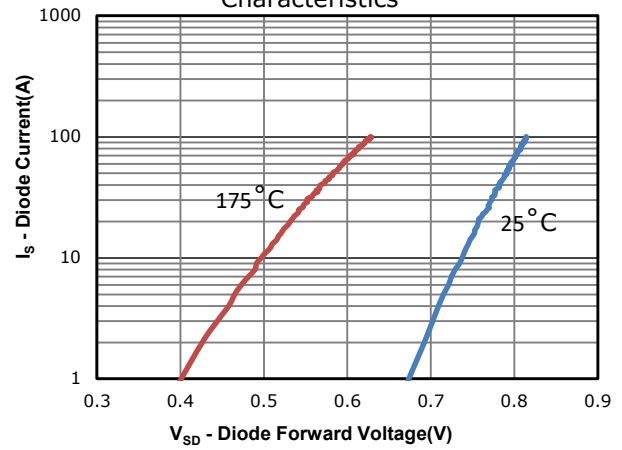


Fig 11: Power Dissipation

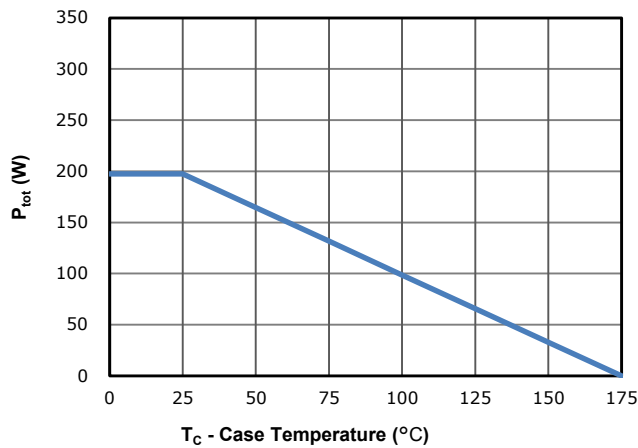


Fig 12: Drain Current Derating

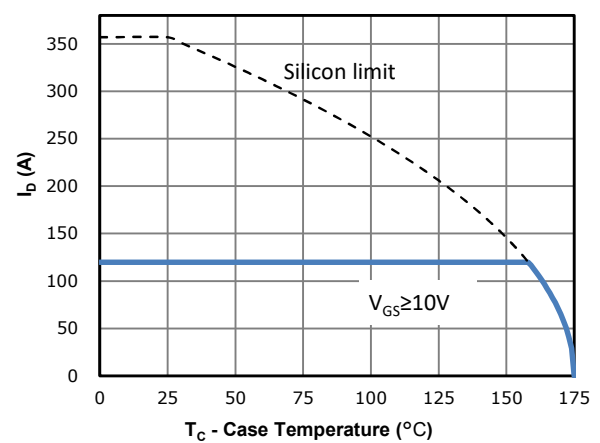


Fig 13: Safe Operating Area

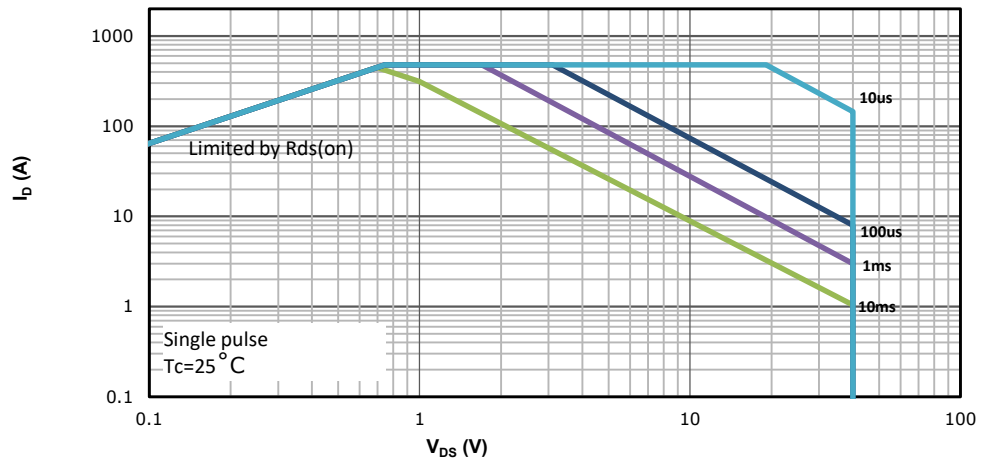
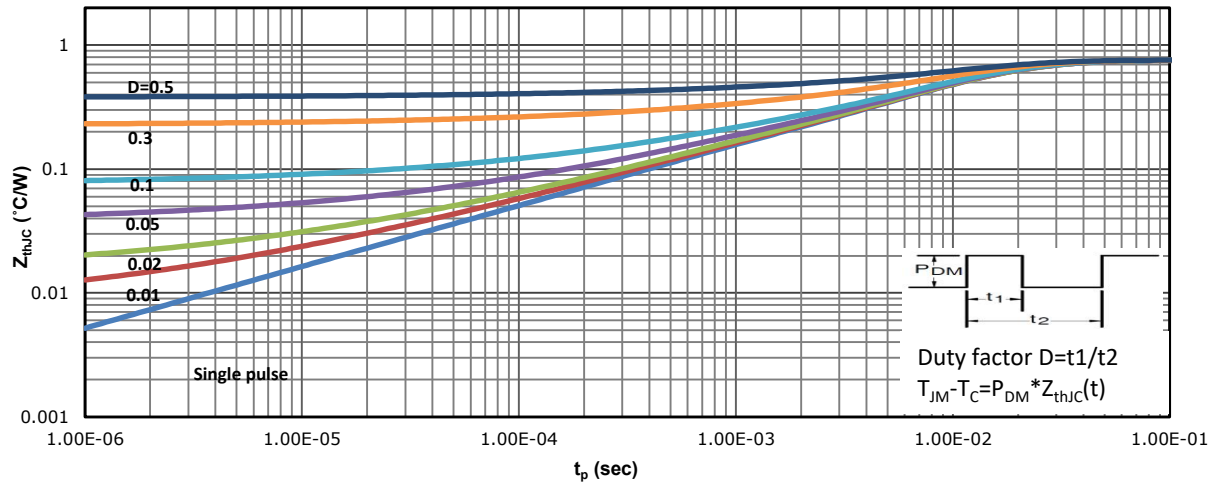
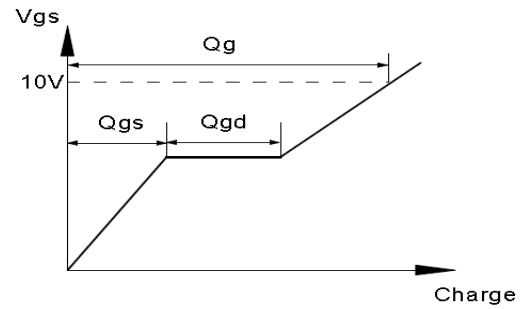
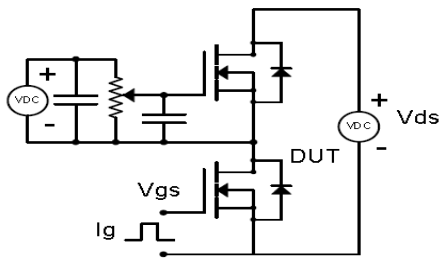


Fig 14: Max. Transient Thermal Impedance

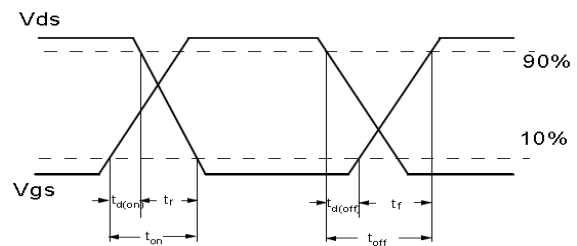
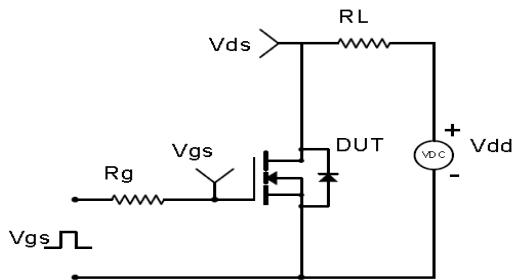


Test Circuit & Waveform

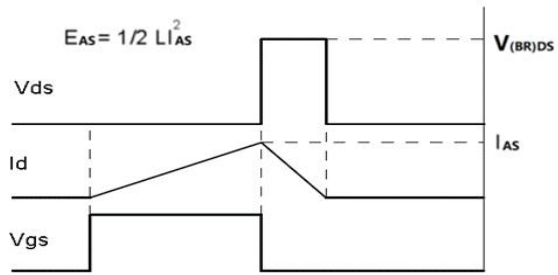
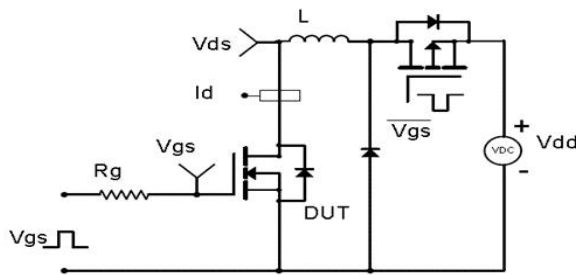
Gate Charge Test Circuit & Waveform



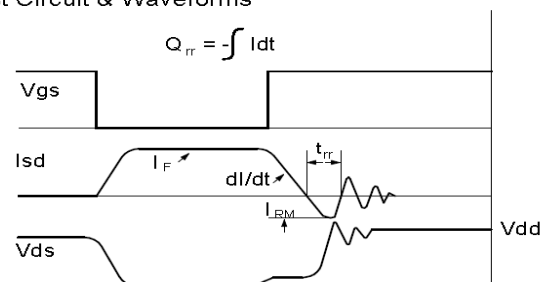
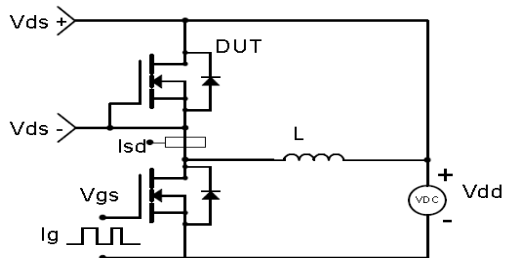
Resistive Switching Test Circuit & Waveforms



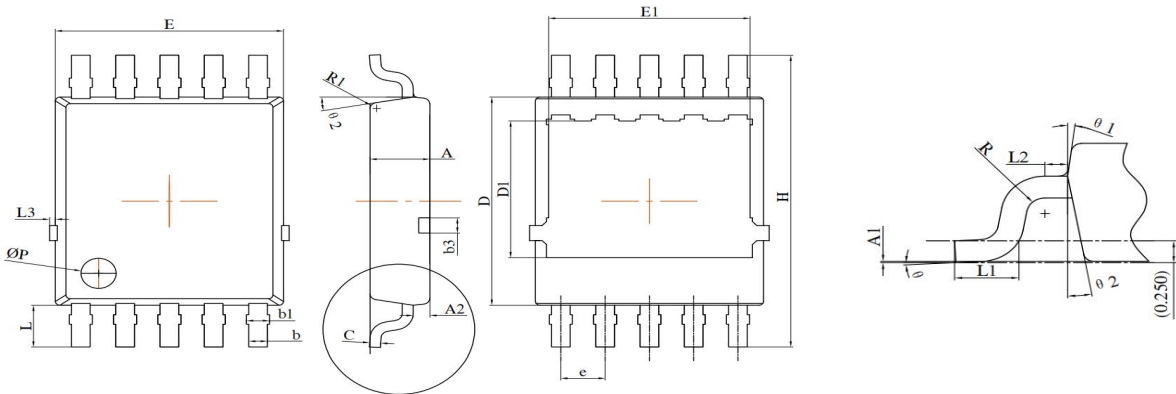
Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms



Package Outline: TCOP10



SYMBOL	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.25	1.45	0.049	0.057
A1	0.00	0.10	0.000	0.004
A2	0.275	0.475	0.011	0.019
b	0.32	0.52	0.013	0.020
b1	0.37	0.67	0.015	0.026
c	0.20	0.30	0.008	0.012
D	5.33	5.63	0.210	0.222
D1	3.45	3.75	0.136	0.148
E	5.05	5.25	0.199	0.207
E1	4.30	4.80	0.169	0.189
e	1.00bsc		1.00bsc	
H	7.48	7.88	0.294	0.310
L	0.95	1.25	0.037	0.049
L1	0.50	0.80	0.020	0.031
L2	0.16	0.36	0.006	0.014
L3	0.00	0.15	0.000	0.006
P	0.65	0.95	0.026	0.037
R	0.10	0.28	0.004	0.011
R1	0.10	0.25	0.004	0.010
θ	0°	6°	0°	6°
θ1	5°	9°	5°	9°
θ2	8°	12°	8°	12°

Revision History

Revision	Date	Major changes
1.3	2025/6/11	Update Rjc/Rja max,update Zth,Trr/Qrr
1.4	2025/11/3	Update Fig1&Fig2;
2.0	2025/12/17	Update Ron (max) from 0.75 to 0.79; I _{DSS} test conditon from 150°C to 125°C

Disclaimer

Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.

The product is not intended for use in applications that require extraordinary levels of quality and reliability, such as aviation/aerospace and life-support devices or systems.

Buyer is responsible for its products and applications using PingWei products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by PingWei.

"Typical" parameters which may be provided in PingWei data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts

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